## NSN 5961-01-329-4371

**Fiig:** A110a0



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-329-4371 **Inclosure Material:** Metal **Overall Length:** Between 0.110 inches and 0.120 inches **Terminal Length:** Between 0.018 inches and 0.021 inches **Overall Height:** Between 0.029 inches and 0.037 inches **Overall Width:** Between 0.047 inches and 0.055 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-236 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 forward voltage, dc and 150.0 breakdown voltage, dc **Current Rating Per Characteristic:** 100.00 nanoamperes reverse current, dc **Power Rating Per Characteristic:** 250.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No